

# HEF4053B-Q100

## Triple single-pole double-throw analog switch

Rev. 1 — 22 February 2013

Product data sheet

### 1. General description

The HEF4053B-Q100 is a triple single-pole double-throw (SPDT) analog switch, suitable for use as an analog or digital multiplexer/demultiplexer. Each switch has a digital select input ( $S_n$ ), two independent inputs/outputs ( $nY0$  and  $nY1$ ) and a common input/output ( $nZ$ ). All three switches share an enable input ( $\bar{E}$ ). A HIGH on  $\bar{E}$  causes all switches into the high-impedance OFF-state, independent of  $S_n$ .

$V_{DD}$  and  $V_{SS}$  are the supply voltage connections for the digital control inputs ( $S_n$  and  $\bar{E}$ ). The  $V_{DD}$  to  $V_{SS}$  range is 3 V to 15 V. The analog inputs/outputs ( $nY0$ ,  $nY1$  and  $nZ$ ) can swing between  $V_{DD}$  as a positive limit and  $V_{EE}$  as a negative limit.  $V_{DD} - V_{EE}$  may not exceed 15 V. Unused inputs must be connected to  $V_{DD}$ ,  $V_{SS}$ , or another input. For operation as a digital multiplexer/demultiplexer,  $V_{EE}$  is connected to  $V_{SS}$  (typically ground).  $V_{EE}$  and  $V_{SS}$  are the supply voltage connections for the switches.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V ( $C = 200\text{ pF}$ ,  $R = 0\text{ }\Omega$ )
- Complies with JEDEC standard JESD 13-B

### 3. Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

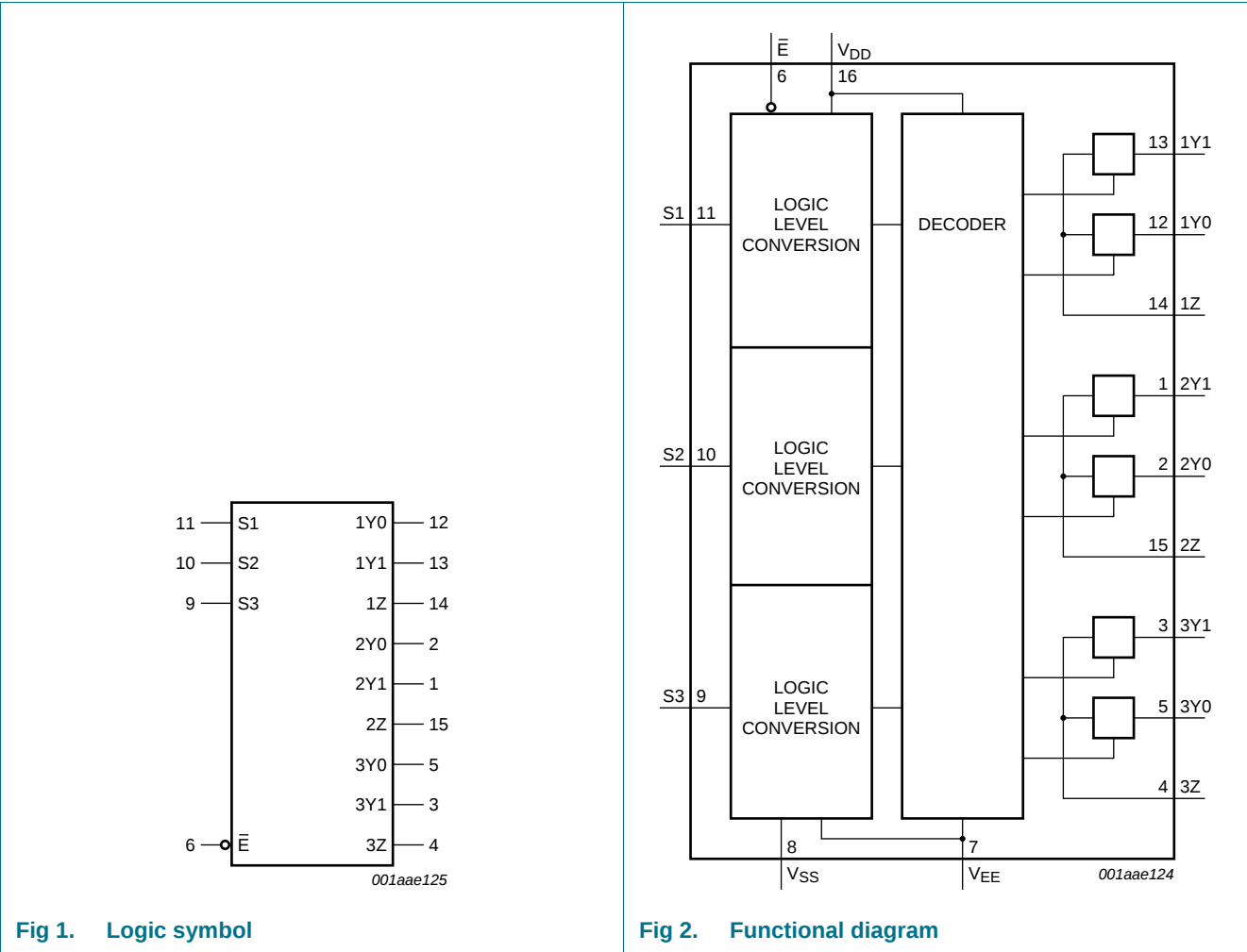


4. Ordering information

Table 1. Ordering information  
All types operate from -40 °C to +125 °C.

| Type number     | Package |                                                                        | Version  |
|-----------------|---------|------------------------------------------------------------------------|----------|
|                 | Name    | Description                                                            |          |
| HEF4053BT-Q100  | SO16    | plastic small outline package; 16 leads; body width 3.9 mm             | SOT109-1 |
| HEF4053BTT-Q100 | TSSOP16 | plastic thin shrink small outline package; 16 leads; body width 4.4 mm | SOT403-1 |

5. Functional diagram



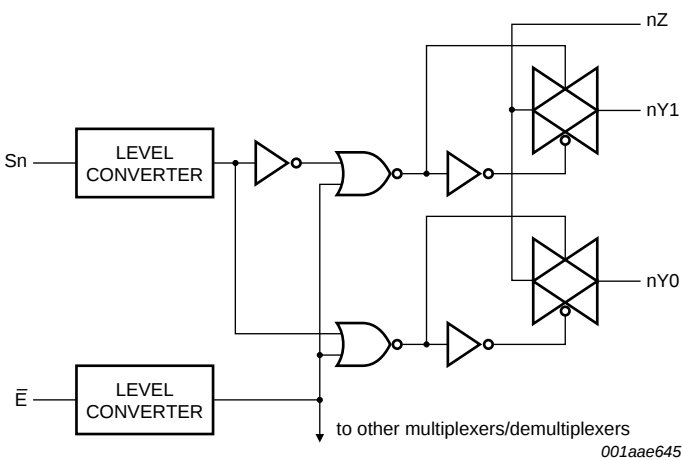


Fig 3. Logic diagram (one multiplexer/demultiplexer)

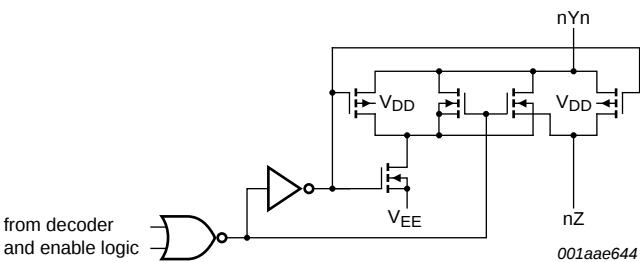


Fig 4. Schematic diagram (one switch)

6. Pinning information

6.1 Pinning

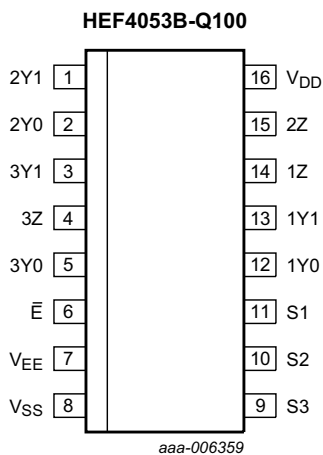


Fig 5. Pin configuration for SOT109-1 (SO16)

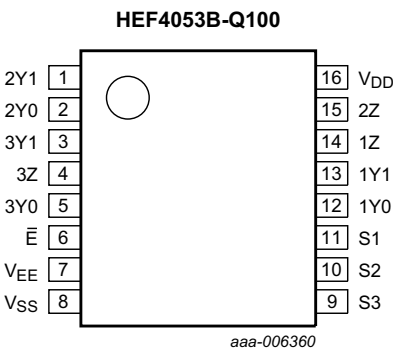


Fig 6. Pin configuration for SOT403-1 (TSSOP16)

## 6.2 Pin description

Table 2. Pin description

| Symbol         | Pin       | Description                 |
|----------------|-----------|-----------------------------|
| $\overline{E}$ | 6         | enable input (active LOW)   |
| $V_{EE}$       | 7         | supply voltage              |
| $V_{SS}$       | 8         | ground supply voltage       |
| S1, S2, S3     | 11, 10, 9 | select input                |
| 1Y0, 2Y0, 3Y0  | 12, 2, 5  | independent input or output |
| 1Y1, 2Y1, 3Y1  | 13, 1, 3  | independent input or output |
| 1Z, 2Z, 3Z     | 14, 15, 4 | independent output or input |
| $V_{DD}$       | 16        | supply voltage              |

## 7. Functional description

Table 3. Function table [\[1\]](#)

| Inputs         |    | Channel on   |
|----------------|----|--------------|
| $\overline{E}$ | Sn |              |
| L              | L  | nY0 to nZ    |
| L              | H  | nY1 to nZ    |
| H              | X  | switches OFF |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

## 8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to  $V_{SS} = 0$  V (ground).

| Symbol    | Parameter               | Conditions                                                               | Min                     | Max            | Unit |
|-----------|-------------------------|--------------------------------------------------------------------------|-------------------------|----------------|------|
| $V_{DD}$  | supply voltage          |                                                                          | -0.5                    | +18            | V    |
| $V_{EE}$  | supply voltage          | referenced to $V_{DD}$                                                   | <a href="#">[1]</a> -18 | +0.5           | V    |
| $I_{IK}$  | input clamping current  | pins Sn and $\overline{E}$ ;<br>$V_I < -0.5$ V or $V_I > V_{DD} + 0.5$ V | -                       | $\pm 10$       | mA   |
| $V_I$     | input voltage           |                                                                          | -0.5                    | $V_{DD} + 0.5$ | V    |
| $I_{I/O}$ | input/output current    |                                                                          | -                       | $\pm 10$       | mA   |
| $I_{DD}$  | supply current          |                                                                          | -                       | 50             | mA   |
| $T_{stg}$ | storage temperature     |                                                                          | -65                     | +150           | °C   |
| $T_{amb}$ | ambient temperature     |                                                                          | -40                     | +125           | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C                                            | <a href="#">[2]</a>     |                |      |
|           |                         | SO16 package                                                             | -                       | 500            | mW   |
|           |                         | TSSOP16 package                                                          | -                       | 500            | mW   |
| P         | power dissipation       | per output                                                               | -                       | 100            | mW   |

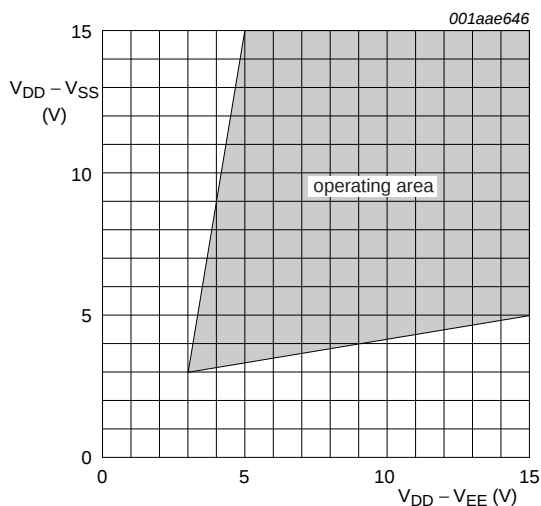
[1] To avoid drawing  $V_{DD}$  current out of terminal Z, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no  $V_{DD}$  current will flow out of terminals nYn, and in this case there is no limit for the voltage drop across the switch, but the voltages at nYn and Z may not exceed  $V_{DD}$  or  $V_{EE}$ .

- [2] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.  
For TSSOP16 package:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

## 9. Recommended operating conditions

**Table 5. Recommended operating conditions**

| Symbol              | Parameter                           | Conditions                   | Min | Typ | Max      | Unit            |
|---------------------|-------------------------------------|------------------------------|-----|-----|----------|-----------------|
| $V_{DD}$            | supply voltage                      | see <a href="#">Figure 7</a> | 3   | -   | 15       | V               |
| $V_I$               | input voltage                       |                              | 0   | -   | $V_{DD}$ | V               |
| $T_{amb}$           | ambient temperature                 | in free air                  | -40 | -   | +125     | °C              |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{DD} = 5\text{ V}$        | -   | -   | 3.75     | $\mu\text{s/V}$ |
|                     |                                     | $V_{DD} = 10\text{ V}$       | -   | -   | 0.5      | $\mu\text{s/V}$ |
|                     |                                     | $V_{DD} = 15\text{ V}$       | -   | -   | 0.08     | $\mu\text{s/V}$ |



**Fig 7. Operating area as a function of the supply voltages**

## 10. Static characteristics

**Table 6. Static characteristics**

$V_{SS} = V_{EE} = 0\text{ V}$ ;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

| Symbol   | Parameter                | Conditions                     | $V_{DD}$ | $T_{amb} = -40\text{ °C}$ |           | $T_{amb} = 25\text{ °C}$ |           | $T_{amb} = 85\text{ °C}$ |           | $T_{amb} = 125\text{ °C}$ |           | Unit          |
|----------|--------------------------|--------------------------------|----------|---------------------------|-----------|--------------------------|-----------|--------------------------|-----------|---------------------------|-----------|---------------|
|          |                          |                                |          | Min                       | Max       | Min                      | Max       | Min                      | Max       | Min                       | Max       |               |
| $V_{IH}$ | HIGH-level input voltage | $ I_O  < 1\text{ }\mu\text{A}$ | 5 V      | 3.5                       | -         | 3.5                      | -         | 3.5                      | -         | 3.5                       | -         | V             |
|          |                          |                                | 10 V     | 7.0                       | -         | 7.0                      | -         | 7.0                      | -         | 7.0                       | -         | V             |
|          |                          |                                | 15 V     | 11.0                      | -         | 11.0                     | -         | 11.0                     | -         | 11.0                      | -         | V             |
| $V_{IL}$ | LOW-level input voltage  | $ I_O  < 1\text{ }\mu\text{A}$ | 5 V      | -                         | 1.5       | -                        | 1.5       | -                        | 1.5       | -                         | 1.5       | V             |
|          |                          |                                | 10 V     | -                         | 3.0       | -                        | 3.0       | -                        | 3.0       | -                         | 3.0       | V             |
|          |                          |                                | 15 V     | -                         | 4.0       | -                        | 4.0       | -                        | 4.0       | -                         | 4.0       | V             |
| $I_I$    | input leakage current    |                                | 15 V     | -                         | $\pm 0.1$ | -                        | $\pm 0.1$ | -                        | $\pm 1.0$ | -                         | $\pm 1.0$ | $\mu\text{A}$ |

**Table 6. Static characteristics ...continued**  
 $V_{SS} = V_{EE} = 0\text{ V}$ ;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

| Symbol              | Parameter                 | Conditions                                             | V <sub>DD</sub> | T <sub>amb</sub> = −40 °C |     | T <sub>amb</sub> = 25 °C |      | T <sub>amb</sub> = 85 °C |     | T <sub>amb</sub> = 125 °C |     | Unit |
|---------------------|---------------------------|--------------------------------------------------------|-----------------|---------------------------|-----|--------------------------|------|--------------------------|-----|---------------------------|-----|------|
|                     |                           |                                                        |                 | Min                       | Max | Min                      | Max  | Min                      | Max | Min                       | Max |      |
| I <sub>S(OFF)</sub> | OFF-state leakage current | Z port; all channels OFF; see <a href="#">Figure 8</a> | 15 V            | -                         | -   | -                        | 1000 | -                        | -   | -                         | -   | nA   |
|                     |                           | Y port; per channel; see <a href="#">Figure 9</a>      | 15 V            | -                         | -   | -                        | 200  | -                        | -   | -                         | -   | nA   |
| I <sub>DD</sub>     | supply current            | I <sub>O</sub> = 0 A                                   | 5 V             | -                         | 5   | -                        | 5    | -                        | 150 | -                         | 150 | μA   |
|                     |                           |                                                        | 10 V            | -                         | 10  | -                        | 10   | -                        | 300 | -                         | 300 | μA   |
|                     |                           |                                                        | 15 V            | -                         | 20  | -                        | 20   | -                        | 600 | -                         | 600 | μA   |
| C <sub>I</sub>      | input capacitance         | S <sub>n</sub> , $\overline{\text{E}}$ inputs          | -               | -                         | -   | -                        | 7.5  | -                        | -   | -                         | -   | pF   |

10.1 Test circuits

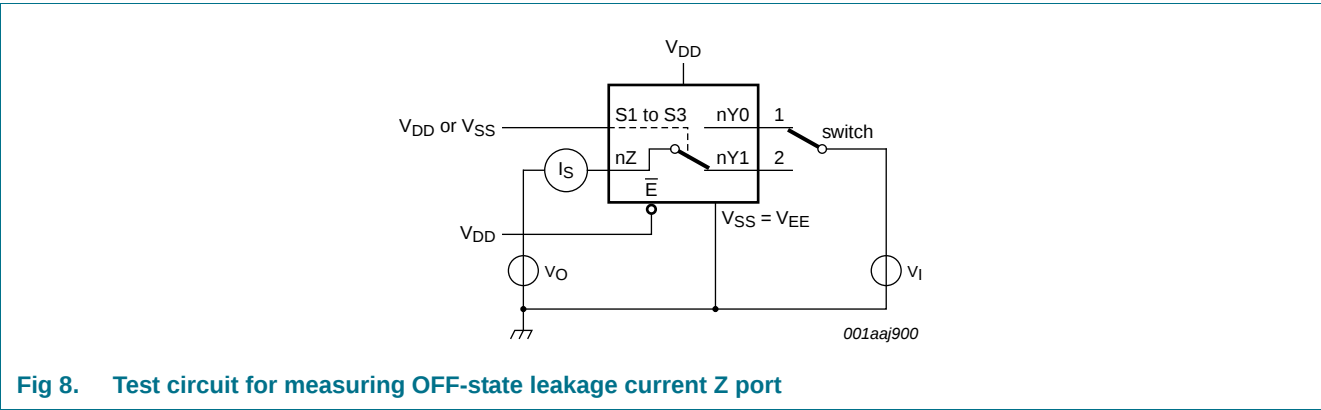


Fig 8. Test circuit for measuring OFF-state leakage current Z port

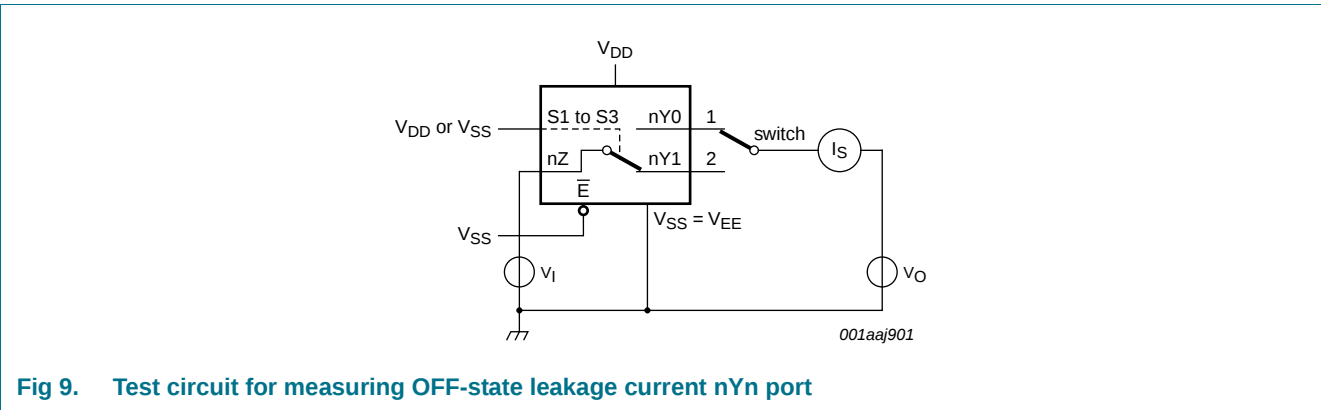


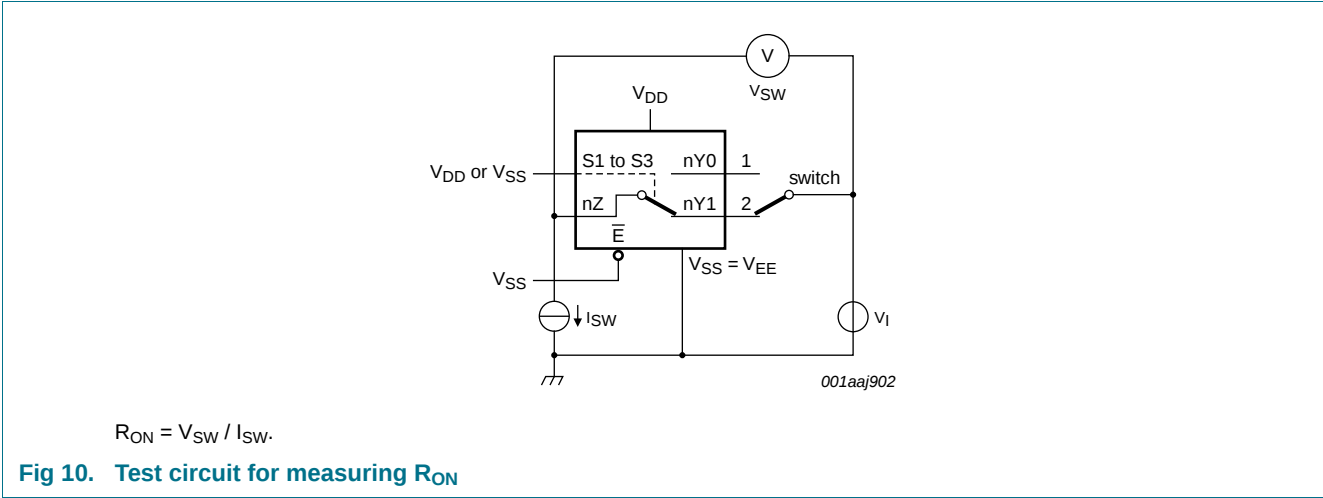
Fig 9. Test circuit for measuring OFF-state leakage current nYn port

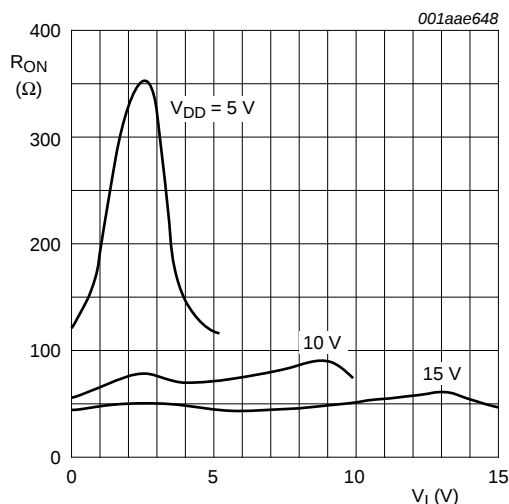
10.2 ON resistance

Table 7. ON resistance  
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $I_{SW} = 200\text{ }\mu\text{A}$ ;  $V_{SS} = V_{EE} = 0\text{ V}$ .

| Symbol          | Parameter                               | Conditions                                                                                             | $V_{DD} - V_{EE}$ | Typ | Max  | Unit     |
|-----------------|-----------------------------------------|--------------------------------------------------------------------------------------------------------|-------------------|-----|------|----------|
| $R_{ON(peak)}$  | ON resistance (peak)                    | $V_I = 0\text{ V to }V_{DD} - V_{EE}$ ;<br>see <a href="#">Figure 10</a> and <a href="#">Figure 11</a> | 5 V               | 350 | 2500 | $\Omega$ |
|                 |                                         |                                                                                                        | 10 V              | 80  | 245  | $\Omega$ |
|                 |                                         |                                                                                                        | 15 V              | 60  | 175  | $\Omega$ |
| $R_{ON(rail)}$  | ON resistance (rail)                    | $V_I = 0\text{ V}$ ; see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>                       | 5 V               | 115 | 340  | $\Omega$ |
|                 |                                         |                                                                                                        | 10 V              | 50  | 160  | $\Omega$ |
|                 |                                         |                                                                                                        | 15 V              | 40  | 115  | $\Omega$ |
|                 |                                         | $V_I = V_{DD} - V_{EE}$ ;<br>see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>               | 5 V               | 120 | 365  | $\Omega$ |
|                 |                                         |                                                                                                        | 10 V              | 65  | 200  | $\Omega$ |
|                 |                                         |                                                                                                        | 15 V              | 50  | 155  | $\Omega$ |
| $\Delta R_{ON}$ | ON resistance mismatch between channels | $V_I = 0\text{ V to }V_{DD} - V_{EE}$ ; see <a href="#">Figure 10</a>                                  | 5 V               | 25  | -    | $\Omega$ |
|                 |                                         |                                                                                                        | 10 V              | 10  | -    | $\Omega$ |
|                 |                                         |                                                                                                        | 15 V              | 5   | -    | $\Omega$ |

10.2.1 ON resistance waveform and test circuit



Fig 11. Typical  $R_{ON}$  as a function of input voltage

## 11. Dynamic characteristics

Table 8. Dynamic characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $V_{SS} = V_{EE} = 0\text{ V}$ ; for test circuit see [Figure 15](#).

| Symbol    | Parameter                                    | Conditions                                               | $V_{DD}$ | Typ | Max | Unit |
|-----------|----------------------------------------------|----------------------------------------------------------|----------|-----|-----|------|
| $t_{PHL}$ | HIGH to LOW propagation delay                | nYn, nZ to nZ, nYn; see <a href="#">Figure 12</a>        | 5 V      | 10  | 20  | ns   |
|           |                                              |                                                          | 10 V     | 5   | 10  | ns   |
|           |                                              |                                                          | 15 V     | 5   | 10  | ns   |
|           | Sn to nYn, nZ; see <a href="#">Figure 13</a> |                                                          | 5 V      | 200 | 400 | ns   |
|           |                                              |                                                          | 10 V     | 85  | 170 | ns   |
|           |                                              |                                                          | 15 V     | 65  | 130 | ns   |
| $t_{PLH}$ | LOW to HIGH propagation delay                | nYn, nZ to nZ, nYn; see <a href="#">Figure 12</a>        | 5 V      | 15  | 30  | ns   |
|           |                                              |                                                          | 10 V     | 5   | 10  | ns   |
|           |                                              |                                                          | 15 V     | 5   | 10  | ns   |
|           | Sn to nYn, nZ; see <a href="#">Figure 13</a> |                                                          | 5 V      | 275 | 555 | ns   |
|           |                                              |                                                          | 10 V     | 100 | 200 | ns   |
|           |                                              |                                                          | 15 V     | 65  | 130 | ns   |
| $t_{PHZ}$ | HIGH to OFF-state propagation delay          | $\overline{E}$ to nYn, nZ; see <a href="#">Figure 14</a> | 5 V      | 200 | 400 | ns   |
|           |                                              |                                                          | 10 V     | 115 | 230 | ns   |
|           |                                              |                                                          | 15 V     | 110 | 220 | ns   |
| $t_{PZH}$ | OFF-state to HIGH propagation delay          | $\overline{E}$ to nYn, nZ; see <a href="#">Figure 14</a> | 5 V      | 260 | 525 | ns   |
|           |                                              |                                                          | 10 V     | 95  | 190 | ns   |
|           |                                              |                                                          | 15 V     | 65  | 130 | ns   |
| $t_{PLZ}$ | LOW to OFF-state propagation delay           | $\overline{E}$ to nYn, nZ; see <a href="#">Figure 14</a> | 5 V      | 200 | 400 | ns   |
|           |                                              |                                                          | 10 V     | 120 | 245 | ns   |
|           |                                              |                                                          | 15 V     | 110 | 215 | ns   |

Table 8. Dynamic characteristics ...continued  
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $V_{SS} = V_{EE} = 0\text{ V}$ ; for test circuit see Figure 15.

| Symbol    | Parameter                          | Conditions                          | $V_{DD}$ | Typ | Max | Unit |
|-----------|------------------------------------|-------------------------------------|----------|-----|-----|------|
| $t_{PZL}$ | OFF-state to LOW propagation delay | $\bar{E}$ to nYn, nZ; see Figure 14 | 5 V      | 280 | 565 | ns   |
|           |                                    |                                     | 10 V     | 105 | 205 | ns   |
|           |                                    |                                     | 15 V     | 70  | 140 | ns   |

11.1 Waveforms and test circuit

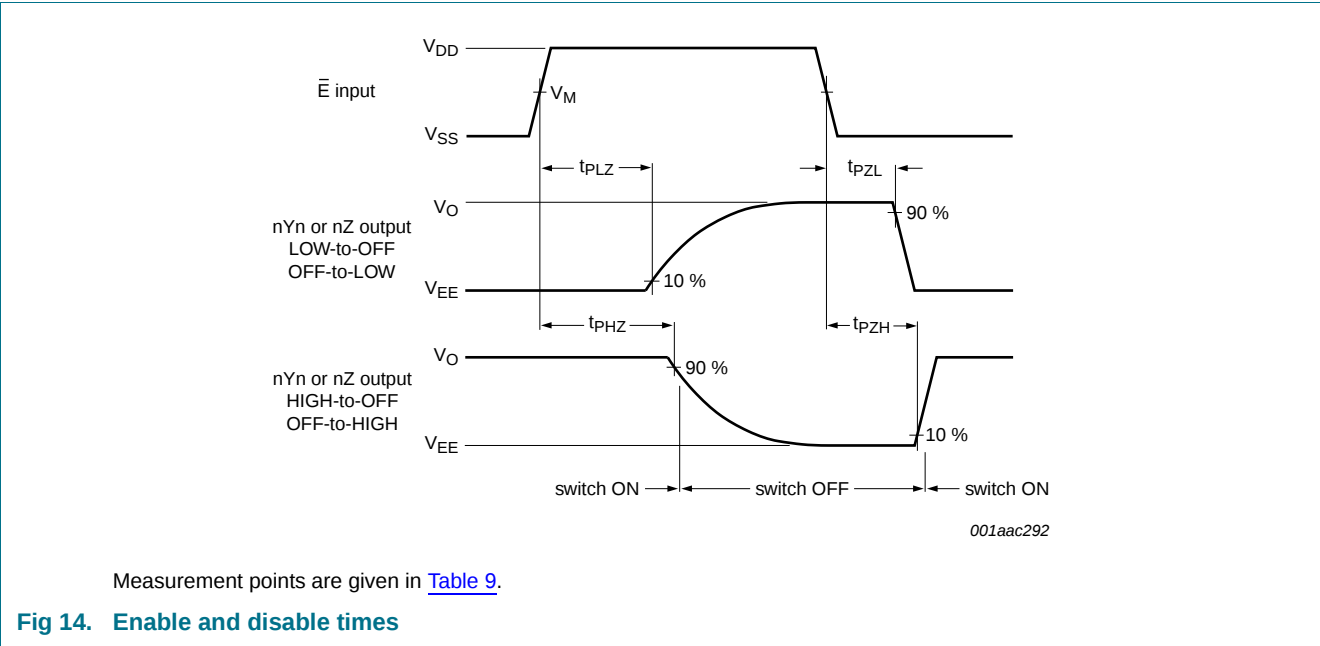
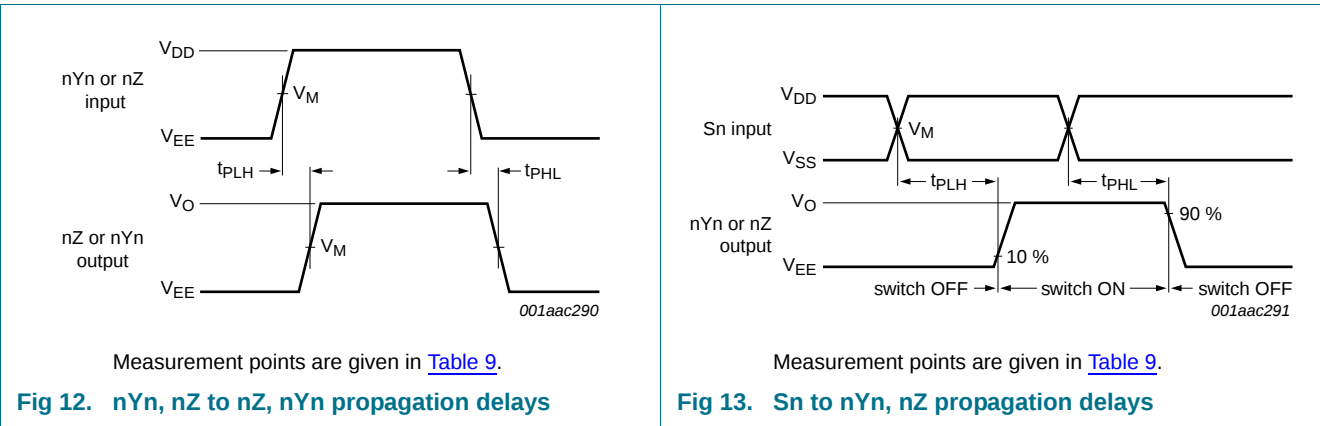
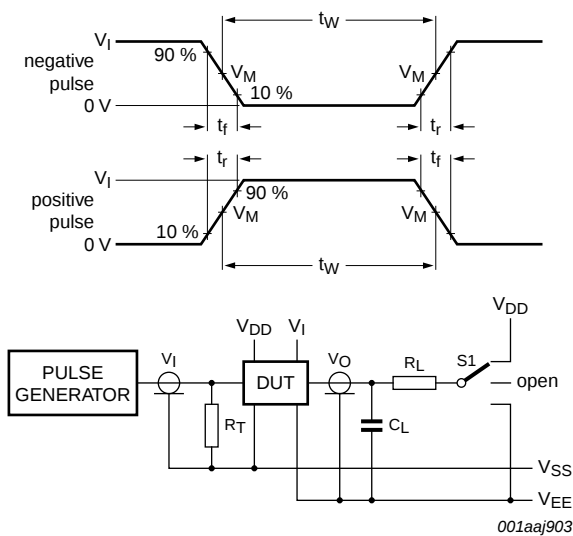


Table 9. Measurement points

| Supply voltage | Input       | Output      |
|----------------|-------------|-------------|
| $V_{DD}$       | $V_M$       | $V_M$       |
| 5 V to 15 V    | $0.5V_{DD}$ | $0.5V_{DD}$ |



Test data is given in [Table 10](#).

Definitions:

DUT = Device Under Test.

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$C_L$  = Load capacitance including test jig and probe.

$R_L$  = Load resistance.

Fig 15. Test circuit for measuring switching times

Table 10. Test data

| Input                |                      |              |             | Load  |               | S1 position          |           |                    |                    |          |
|----------------------|----------------------|--------------|-------------|-------|---------------|----------------------|-----------|--------------------|--------------------|----------|
| nYn, nZ              | Sn and $\bar{E}$     | $t_r, t_f$   | $V_M$       | $C_L$ | $R_L$         | $t_{PHL}$ [1]        | $t_{PLH}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ | other    |
| $V_{DD}$ or $V_{EE}$ | $V_{DD}$ or $V_{SS}$ | $\leq 20$ ns | $0.5V_{DD}$ | 50 pF | 10 k $\Omega$ | $V_{DD}$ or $V_{EE}$ | $V_{EE}$  | $V_{EE}$           | $V_{DD}$           | $V_{EE}$ |

[1] For nYn to nZ or nZ to nYn propagation delays use  $V_{EE}$ . For Sn to nYn or nZ propagation delays use  $V_{DD}$ .

## 11.2 Additional dynamic parameters

**Table 11. Additional dynamic characteristics**
 $V_{SS} = V_{EE} = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

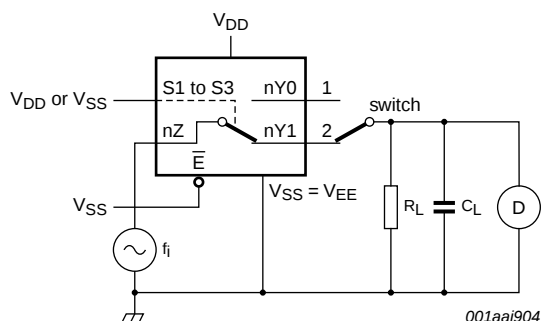
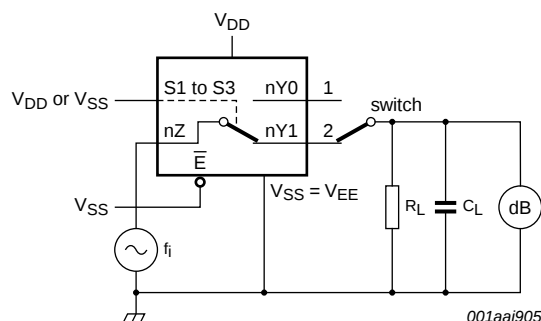
| Symbol              | Parameter                 | Conditions                                                                                                                         | $V_{DD}$ | Typ      | Max | Unit |
|---------------------|---------------------------|------------------------------------------------------------------------------------------------------------------------------------|----------|----------|-----|------|
| THD                 | total harmonic distortion | see Figure 16; $R_L = 10\text{ k}\Omega$ ; $C_L = 15\text{ pF}$ ;<br>channel ON; $V_I = 0.5V_{DD}$ (p-p);<br>$f_i = 1\text{ kHz}$  | 5 V      | [1] 0.25 | -   | %    |
|                     |                           |                                                                                                                                    | 10 V     | [1] 0.04 | -   | %    |
|                     |                           |                                                                                                                                    | 15 V     | [1] 0.04 | -   | %    |
| $f_{(-3\text{dB})}$ | –3 dB frequency response  | see Figure 17; $R_L = 1\text{ k}\Omega$ ; $C_L = 5\text{ pF}$ ;<br>channel ON; $V_I = 0.5V_{DD}$ (p-p)                             | 5 V      | [1] 13   | -   | MHz  |
|                     |                           |                                                                                                                                    | 10 V     | [1] 40   | -   | MHz  |
|                     |                           |                                                                                                                                    | 15 V     | [1] 70   | -   | MHz  |
| $\alpha_{iso}$      | isolation (OFF-state)     | see Figure 18; $f_i = 1\text{ MHz}$ ; $R_L = 1\text{ k}\Omega$ ;<br>$C_L = 5\text{ pF}$ ; channel OFF;<br>$V_I = 0.5V_{DD}$ (p-p)  | 10 V     | [1] –50  | -   | dB   |
| $V_{ct}$            | crosstalk voltage         | digital inputs to switch; see Figure 19;<br>$R_L = 10\text{ k}\Omega$ ; $C_L = 15\text{ pF}$ ;<br>E or Sn = $V_{DD}$ (square-wave) | 10 V     | 50       | -   | mV   |
| Xtalk               | crosstalk                 | between switches; see Figure 20;<br>$f_i = 1\text{ MHz}$ ; $R_L = 1\text{ k}\Omega$ ;<br>$V_I = 0.5V_{DD}$ (p-p)                   | 10 V     | [1] –50  | -   | dB   |

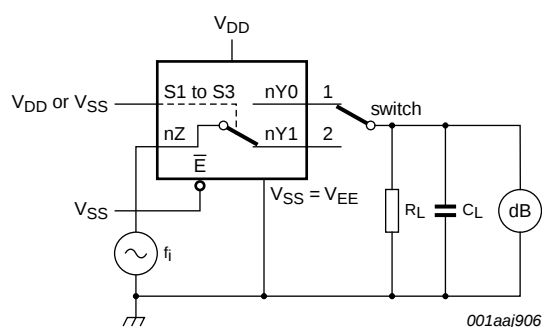
[1]  $f_i$  is biased at  $0.5 V_{DD}$ ;  $V_I = 0.5V_{DD}$  (p-p).

**Table 12. Dynamic power dissipation  $P_D$** 
 $P_D$  can be calculated from the formulas shown;  $V_{EE} = V_{SS} = 0\text{ V}$ ;  $t_r = t_f \leq 20\text{ ns}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

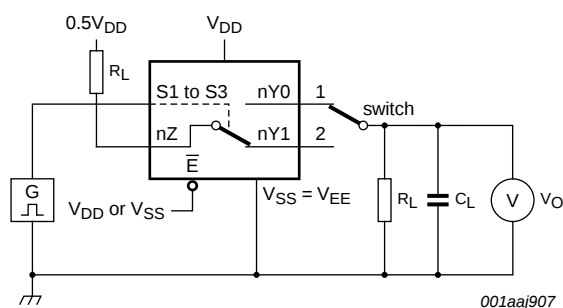
| Symbol | Parameter                 | $V_{DD}$ | Typical formula for $P_D$ ( $\mu\text{W}$ )                       | where:                                                                                                                      |
|--------|---------------------------|----------|-------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------|
| $P_D$  | dynamic power dissipation | 5 V      | $P_D = 2500 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$  | $f_i$ = input frequency in MHz;                                                                                             |
|        |                           | 10 V     | $P_D = 11500 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$ | $f_o$ = output frequency in MHz;                                                                                            |
|        |                           | 15 V     | $P_D = 29000 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$ | $C_L$ = output load capacitance in pF;<br>$V_{DD}$ = supply voltage in V;<br>$\Sigma(C_L \times f_o)$ = sum of the outputs. |

### 11.2.1 Test circuits

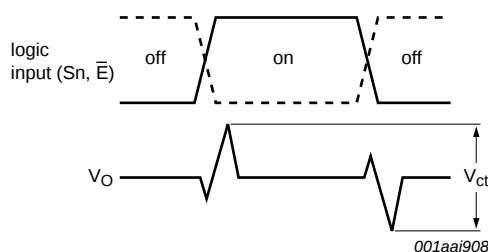

**Fig 16. Test circuit for measuring total harmonic distortion**

**Fig 17. Test circuit for measuring frequency response**



**Fig 18. Test circuit for measuring isolation (OFF-state)**

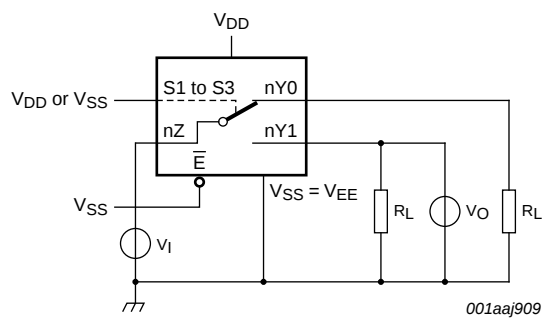


a. Test circuit

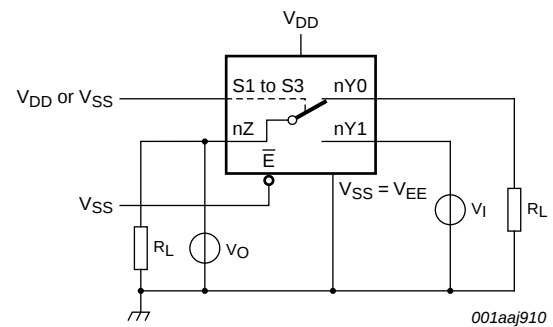


### b. Input and output pulse definitions

**Fig 19. Test circuit for measuring crosstalk voltage between digital inputs and switch**



a. Switch closed condition



b. Switch open condition

**Fig 20. Test circuit for measuring crosstalk between switches**

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm SOT109-1

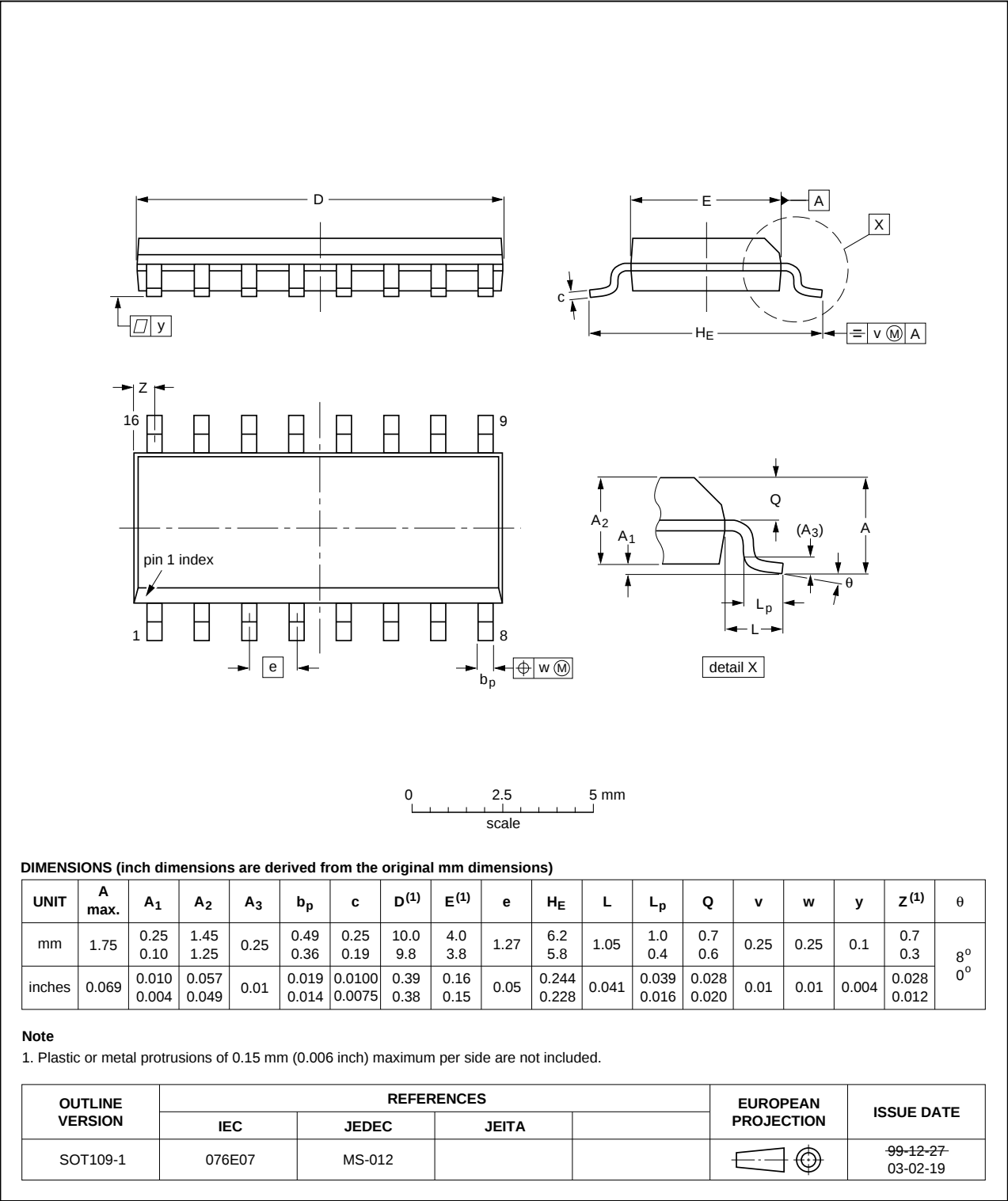


Fig 21. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

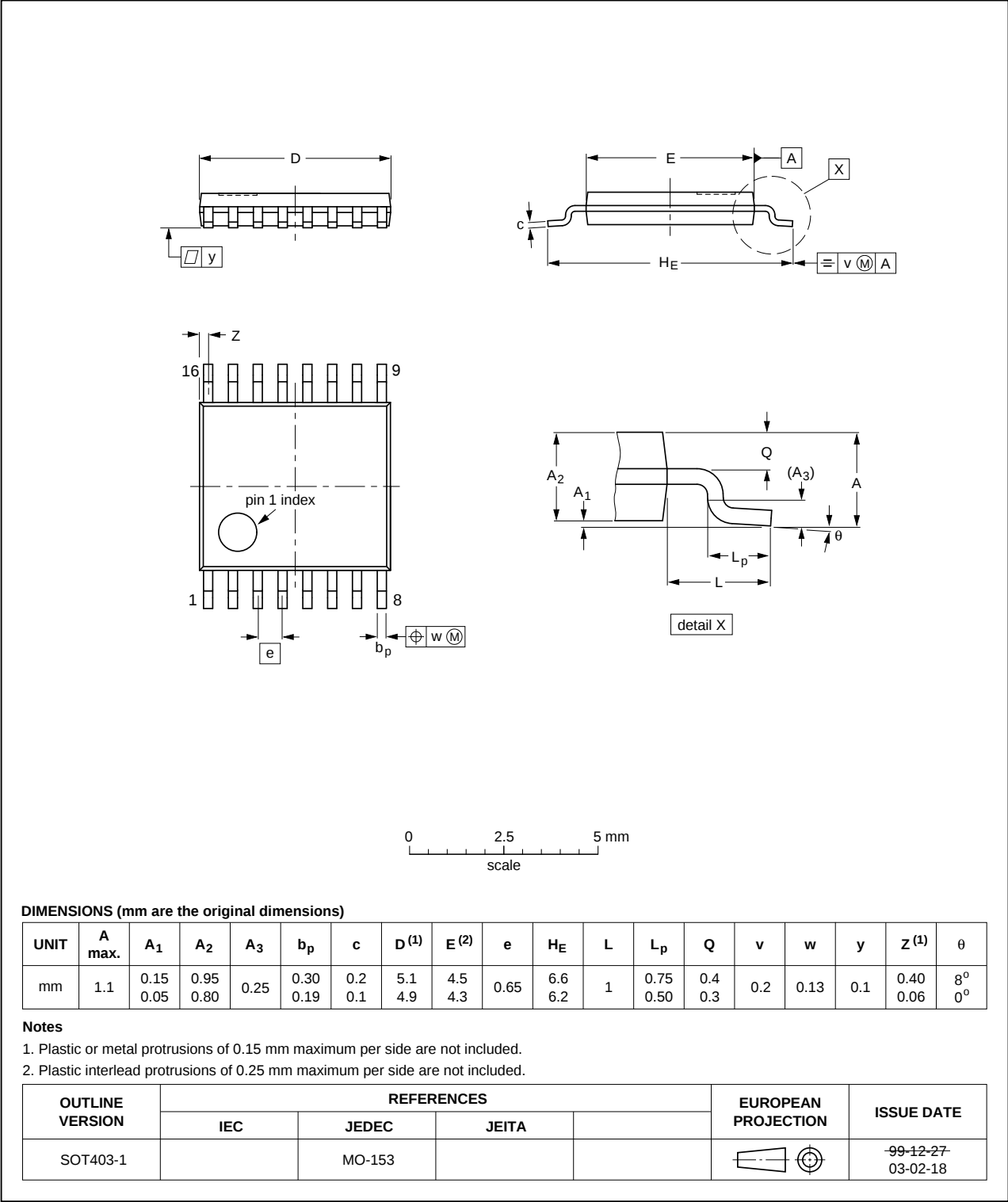


Fig 22. Package outline SOT403-1 (TSSOP16)

## 13. Abbreviations

Table 13. Abbreviations

| Acronym | Description             |
|---------|-------------------------|
| HBM     | Human Body Model        |
| ESD     | ElectroStatic Discharge |
| MM      | Machine Model           |
| MIL     | Military                |

## 14. Revision history

Table 14. Revision history

| Document ID       | Release date | Data sheet status  | Change notice | Supersedes |
|-------------------|--------------|--------------------|---------------|------------|
| HEF4053B_Q100 v.1 | 20130222     | Product data sheet | -             | -          |

## 15. Legal information

### 15.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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